



### Rev.01 - 09 January 2025

**Product data sheet** 

### 1. General description

Planar passivated very sensitive gate four quadrant triac in a TO92 plastic package intended for use in applications requiring direct interfacing to logic ICs and low power gate drivers.

### 2. Features and benefits

- High blocking voltage capability
- Very sensitive gate
- · Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Direct interfacing to logic level ICs
- Direct interfacing to low power gate drive circuits

### 3. Applications

- Industrial process control
- General purpose low power motor control
- Home appliances
- Low power AC Fan controllers

### 4. Quick reference data

### Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit
Absolute	e maximum rating						
$V_{\text{DRM}}$	repetitive peak off-state voltage				800		V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; Fig. 1; Fig. 2			2		А
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 20 ms; Fig. 3; Fig. 4		16			A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms		17.5			А
T <sub>j</sub>	operating junction temperature			-40 to 125		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics	·					
I <sub>GT</sub>	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T <sub>1</sub> = 25 °C; <u>Fig. 6</u>		-	-	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	-	5	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	-	5	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2- G+; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	-	7	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>		-	-	10	mA
V <sub>T</sub>	on-state voltage	I <sub>τ</sub> = 2 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>		-	1.35	1.65	V

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Dynamic characteristics							
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM} = 536 \text{ V}; \text{ T}_{\text{j}} = 110 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM}); exponential waveform; gate open circuit; Fig. 11$		20	-	-	V/µs
dV <sub>com</sub> /dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; \text{ T}_i = 110 \text{ °C}; \text{ dI}_{com}/\text{dt} = 0.44$ A/ms; I <sub>T</sub> = 1 A; gate open circuit		1	-	-	V/µs

# **5. Pinning information**

Table 2. P	Fable 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol					
1	T2	main terminal 2		Ν					
2	G	gate	Li L						
3	Τ1	main terminal 1	)               TO-92 (SOT54)	sym051					

# 6. Ordering information

Table 3. Ordering information									
Type number	Package Name	Orderable part number	Packing method	Small packing quantity		Package issue date			
BT232-800D	TO92	BT232-800D,412	Bulk	1000	TO92L	10-May-2021			

# 7. Marking

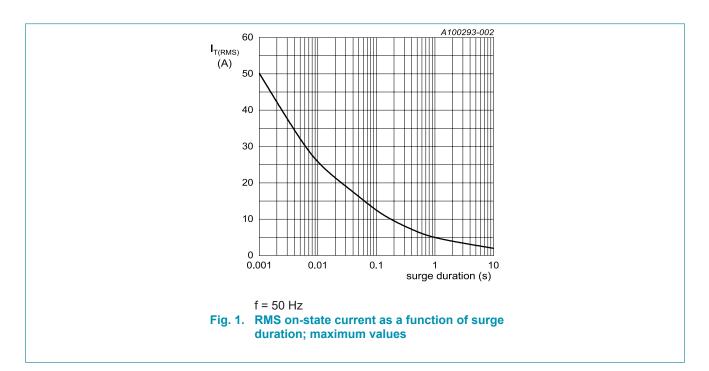
Table 4. Marking codes	
Type number	Marking codes
BT232-800D	232-8D

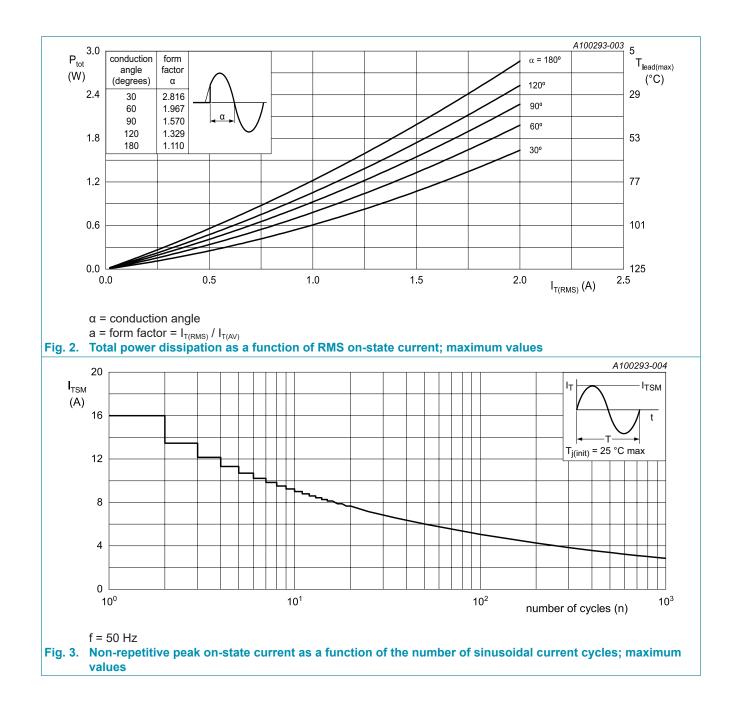
# 8. Limiting values

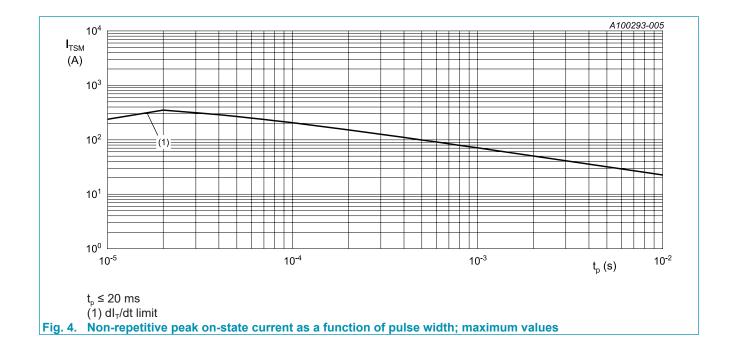
### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage			800	V
$V_{\text{RRM}}$	repetitive peak reverse voltage			800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; Fig. 1; Fig. 2		2	А
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig. 3</u> ; <u>Fig. 4</u>		16	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms		17.5	А
l <sup>2</sup> t	l <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN		1.28	A <sup>2</sup> s
dl⊤/dt	rate of rise of on-state current	I <sub>G</sub> = 20 mA		50	A/µs
I <sub>GM</sub>	peak gate current			1	А
$P_{GM}$	peak gate power			2	W
$P_{G(AV)}$	average gate power	over any 20 ms period		0.1	W
T <sub>stg</sub>	storage temperature			-40 to 150	°C
T <sub>j</sub>	operating junction temperature			-40 to 125	°C

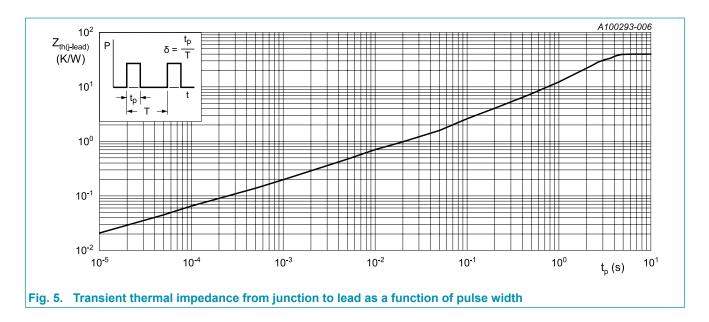






## 9. Thermal characteristics

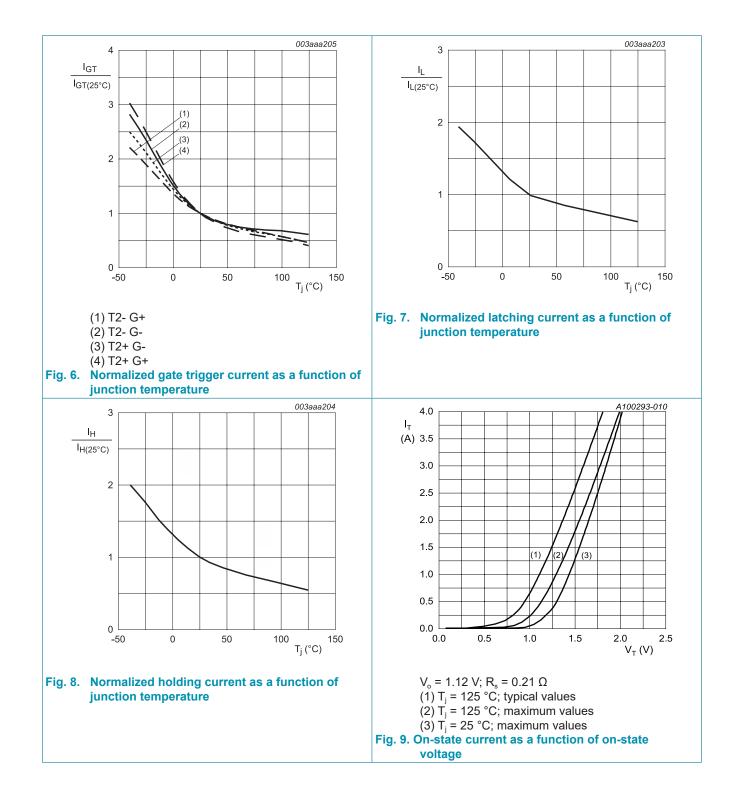
Table 6. Th	able 6. Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	full cycle; <u>Fig. 5</u>		-	40	-	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	full cycle; printed circuit board: lead length = 4 mm		-	150	-	K/W

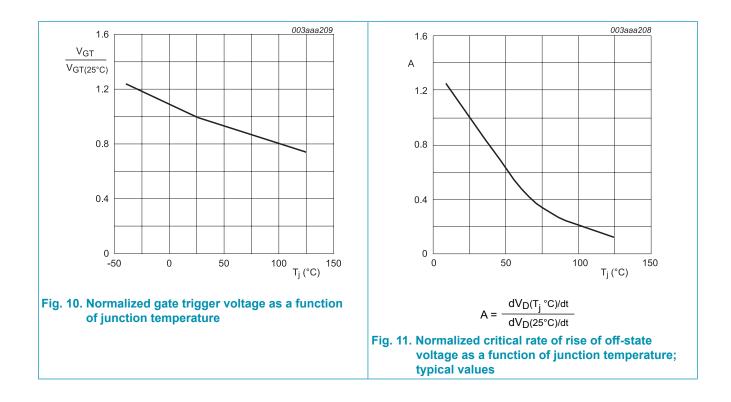


## **10. Characteristics**

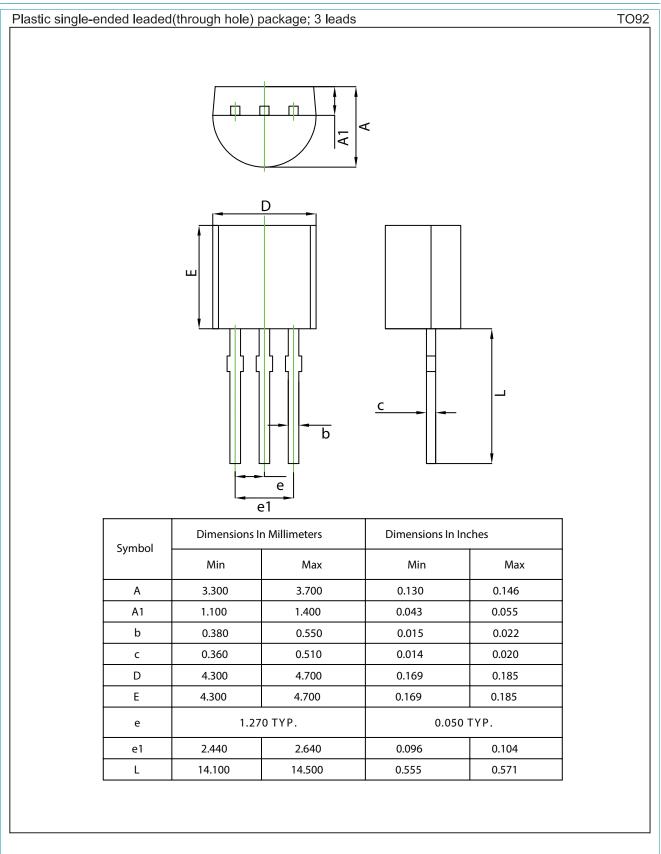
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
Ι <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2+ G+; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	-	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; Fig. 6	-	-	5	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	-	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	-	7	mA
IL	latching current	V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; T2+ G+; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	10	mA
		V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; T2+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	20	mA
		V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2- G+};$ T <sub>j</sub> = 25 °C; Fig. 7	-	-	10	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig.8</u>	-	-	10	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 2 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	1.35	1.65	V
V <sub>GT</sub>	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 10	-	-	1	V
		$V_{\rm D}$ = 800 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C	0.2	-	-	V
I <sub>D</sub>	off-state current	$V_{\rm D}$ = 800 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>D</sub> = 800 V; T <sub>j</sub> = 125 °C	-	-	0.5	mA
I <sub>R</sub>	reverse current	$V_{\rm D}$ = 800 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>D</sub> = 800 V; T <sub>j</sub> = 125 °C	-	-	0.5	mA
Dynamic	characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 110 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit; Fig. 11	20	-	-	V/µs
dV <sub>com</sub> /dt	rate of change of commutating voltage	$V_{D}$ = 400 V; $T_{j}$ = 110 °C; $dI_{com}/dt$ = 0.44 A/ms; $I_{T}$ = 1 A; gate open circuit	1	-	-	V/µs

BT232-800D 4Q Triac





# **11. Package outline**



BT232-800D Product data sheet

# 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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